

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

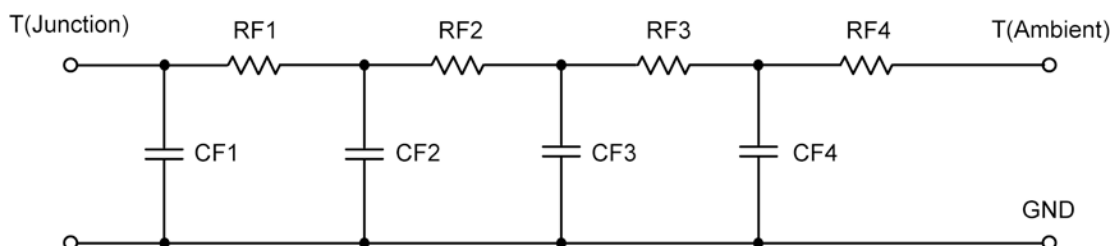
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	4.5059	N/A	12.9701
RT2	15.1163	N/A	3.7290
RT3	23.6813	N/A	7.7290
RT4	56.6965	N/A	15.5719
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.2427 m	N/A	19.2285 m
CT2	14.2046 m	N/A	938.8832 u
CT3	55.0364 m	N/A	9.1418 m
CT4	1.1604	N/A	91.2383 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	9.8525	N/A	3.6758
RF2	26.6485	N/A	16.4151
RF3	12.7628	N/A	14.3239
RF4	50.7362	N/A	5.5852
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	2.2791 m	N/A	525.0524 u
CF2	16.3611 m	N/A	4.6712 m
CF3	203.7842 m	N/A	27.6672 m
CF4	1.0748	N/A	298.4397 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

